## P-Channel 60-V (D-S) MOSFET

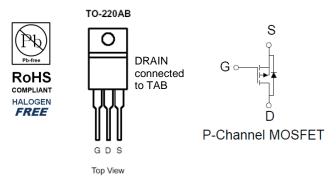
### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

Typical .	Applica	ations:
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- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
-60	12 @ V <sub>GS</sub> = -10V	-90 <sup>a</sup>	
-60	16 @ V <sub>GS</sub> = -4.5V	-90	



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Orain-Source Voltage		$V_{DS}$	-60	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
Continuous Drain Current a	T <sub>A</sub> =25°C	I <sub>D</sub>	-90	Α	
ulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	-360	A	
Continuous Source Current (Diode Conduction) a		I <sub>S</sub>	-90	Α	
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	300	W	
Operating Junction and Storage Temperature Range	· · ·	$T_J,T_stg$	-55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	62.5	°C/W	
Maximum Junction-to-Case	$R_{\theta JC}$	1	C/VV	

1

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

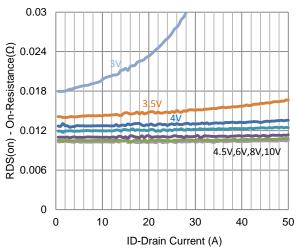
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	1	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
	I <sub>DSS</sub>	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-25	
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-100			Α
Drain-Source On-Resistance	r	$V_{GS} = -10 \text{ V}, I_{D} = -20 \text{ A}$			12	mΩ
	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_{D} = -16 \text{ A}$			16	
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = -15 \text{ V}, I_{D} = -20 \text{ A}$		25		S
Diode Forward Voltage	$V_{SD}$	$I_{S} = -20 \text{ A}, V_{GS} = 0 \text{ V}$		-0.9		V
		Dynamic				
Total Gate Charge	$Q_g$	V 20.V V 45.V		105		nC
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -30 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -20 \text{ A}$		26		
Gate-Drain Charge	$Q_{gd}$	ID = -20 A		51		
Turn-On Delay Time	t <sub>d(on)</sub>	V - 20 V B - 1 5 O		19		ns
Rise Time	t <sub>r</sub>	$V_{DS}$ = -30 V, $R_L$ = 1.5 $\Omega$ , $I_D$ = -20 A, $V_{GEN}$ = -10 V, $R_{GEN}$ = 6 $\Omega$		40		
Turn-Off Delay Time	$t_{d(off)}$			289		
Fall Time	t <sub>f</sub>			108		
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		7267		pF
Output Capacitance	C <sub>oss</sub>			592		
Reverse Transfer Capacitance	$C_{rss}$			411		

#### Notes

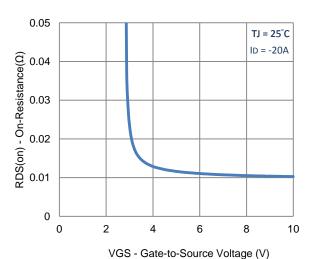
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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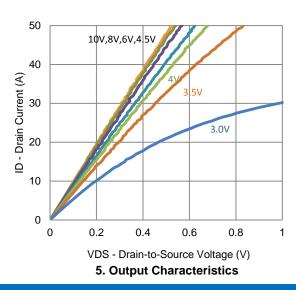
### **Typical Electrical Characteristics**



#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



TJ = 25°C

40

40

40

20

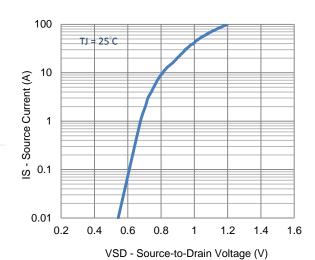
10

0

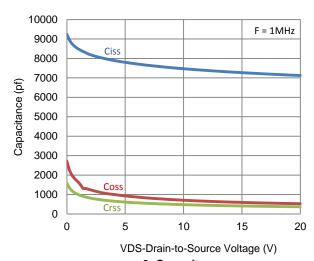
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VGS - Gate-to-Source Voltage (V)

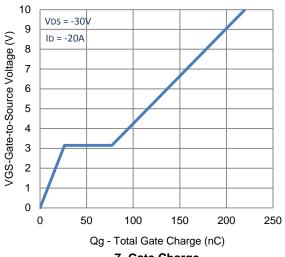
2. Transfer Characteristics

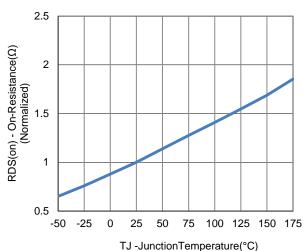


4. Drain-to-Source Forward Voltage

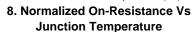


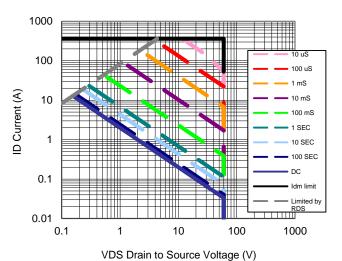
### **Typical Electrical Characteristics**

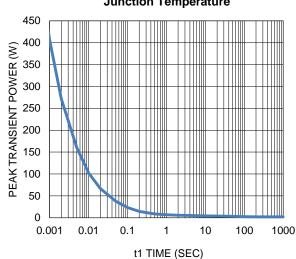




7. Gate Charge

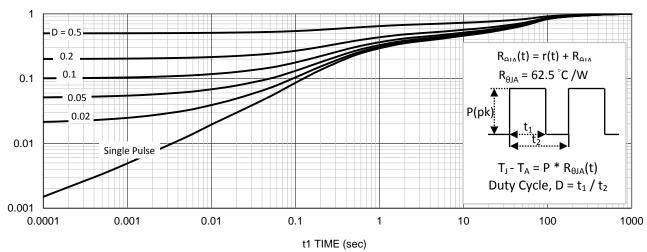






9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

# **Package Information**

